NSN 5961-01-276-9983

A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-276-9983 **Inclosure Material:** Metal **Overall Length:** 6.828 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-9 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.250 inches **Thread Size:** 0.750 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1000.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 800.00 amperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: